

# Dielectric response of thin water films: A thermodynamic perspective

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The surface of a polar liquid presents a special environment for the solvation and organization of charged solutes, which differ from bulk behaviors in important ways. These differences have motivated many attempts to understand electrostatic response at aqueous interfaces in terms of a spatially varying dielectric permittivity, typically concluding that the dielectric constant of interfacial water is significantly lower than in the bulk liquid. Such analyses, however, are complicated by the potentially nonlocal nature of dielectric response over the short length scales of interfacial heterogeneity. Here we circumvent this problem for thin water films by adopting a thermodynamic approach. Using molecular simulations, we calculate the solvent’s contribution to the reversible work of charging a parallel plate capacitor. We find good agreement with a simple dielectric continuum model that assumes bulk dielectric permittivity all the way up to the liquid’s boundary, even for very thin ( $\sim 1$  nm) films. This comparison requires careful attention to the placement of dielectric boundaries between liquid and vapor, which also resolves apparent discrepancies with dielectric imaging experiments.

## I. INTRODUCTION

Interest in confined water has exploded over the last decade or so, owing principally to advances in the fabrication of devices at the nanoscale,<sup>1–3</sup> the potential implications for ‘blue energy’ and desalination,<sup>4</sup> and as means to understand fundamental properties of water<sup>5,6</sup> and its solutions.<sup>7,8</sup> An obvious consequence of the decreasing length scales associated with confinement is an increase in the surface-to-volume ratio of liquid water, which typically amplifies surface-specific effects relative to large sample geometries. The notion of nanoconfined liquid water thus having properties that are inherently different to its bulk counterpart has inspired many attempts to reformulate intensive material parameters typically used to describe the bulk fluid. In particular, many years of investigation along these lines<sup>9–17</sup> has focused on the static dielectric constant  $\epsilon_{\text{liq}}$ , whose role in mediating electrostatic interactions impacts upon, e.g., solvation, capacitance and electrokinetics. Further motivation for such theoretical studies comes from recent dielectric imaging experiments<sup>6</sup> of water confined between two atomically flat walls separated by distances as small as 0.8 nm. These imaging results were inferred to report an interfacial dielectric constant  $\epsilon_{\text{int}} = 2.1$  (relevant to an interfacial region of thickness  $\ell_{\text{int}} \approx 7.5 \pm 1.5$  Å) that dominates the capacitance of a thin water film. This value, typical of a bulk nonpolar liquid, signifies a dramatic departure from the polarizability of bulk water, for which  $\epsilon_{\text{liq}} \approx 80$ .

At the microscopic level, it is well recognized that water’s interfaces exhibit local average properties that differ from the bulk liquid, varying continuously with depth

within a molecular length scale  $\ell_{\text{int}}$  of the surface.<sup>18</sup> Accordingly, many studies have aimed to rationalize confined water’s electrostatic response in terms of a local dielectric constant  $\epsilon(z)$  that varies with position  $z$  along the surface normal.<sup>9–13</sup> Molecular simulations have estimated  $\epsilon(z)$  either from polarization fluctuations, or from response to external electric fields; in either case this approach relies upon interpreting features that have been resolved at a fine scale within a theoretical framework appropriate for macroscopic dielectric materials. In this study, we pursue a different approach. Specifically, we assess the ability of a simple dielectric continuum theory (DCT)—whose dielectric permittivity does not vary with depth  $z$ —to predict free energy differences when water films are subjected to external fields. An advantage of this approach is that it is rooted in thermodynamics, which obviates the need to resolve fluctuations/response at the microscopic level. We will show that simple DCT with  $\epsilon(z) = \epsilon_{\text{bulk}} = \text{const.}$  not only gives a good description of water’s dielectric response under confinement, but it also outperforms models that suppose a lower dielectric constant at the interface. Moreover, we also find that for films comprising just one or two layers of water molecules this simple DCT remains a remarkably reasonable approximation. We show that our analyses are broadly in line with the experimental observations reported in Ref. 6.

The rest of the article is arranged as follows. In Sec. II we briefly review linear response theory for dielectric fluids, calling into question the notion of a permittivity that varies with position over microscopic scales. In Sec. III we analyze the polarization of a confined dielectric continuum under periodic boundary conditions, and derive a finite size correction for the thermodynamics of charging up a parallel plate capacitor. In Sec. IV we use molecular simulations of simple point charge (SPC) models to assess the accuracy of this correction, and compare extrap-

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olated results with DCT predictions. We subsequently assess the performance of more complicated models in Sec. V. In Sec. VI we investigate the length scales at which DCT begins to fail. The sensitivity of the effective dielectric constant to the definition of film thickness is discussed in Sec. VII. We summarize our findings in Sec. VIII.

## II. BRIEF OVERVIEW OF DIELECTRICS

In macroscopic DCT, the polarization  $\mathbf{P}$  in a medium is related to the total electric field  $\mathbf{E}$  by the constitutive relation<sup>19–22</sup>

$$4\pi\mathbf{P}(\mathbf{r}) = \int d\mathbf{r}' [\epsilon(\mathbf{r}, \mathbf{r}') - \mathbf{1}(\mathbf{r}, \mathbf{r}')] \cdot \mathbf{E}(\mathbf{r}'), \quad (1)$$

where  $\epsilon$  is the dielectric tensor,  $\mathbf{1}(\mathbf{r}, \mathbf{r}') = \mathbf{U}\delta(\mathbf{r}, \mathbf{r}')$  with  $\mathbf{U}$  the unit tensor,  $\delta(\mathbf{r}, \mathbf{r}')$  is Dirac's delta function, and the domain of integration is the volume occupied by the medium. Equation 1 is a nonlocal relationship between  $\mathbf{P}$  and  $\mathbf{E}$ . There are two routes to arrive at the more familiar local relationship for a homogeneous, isotropic dielectric

$$4\pi\mathbf{P}(\mathbf{r}) = (\epsilon - 1)\mathbf{E}(\mathbf{r}). \quad (2)$$

The first is to simply assert locality i.e.,  $\epsilon(\mathbf{r}, \mathbf{r}') = \epsilon\mathbf{1}(\mathbf{r}, \mathbf{r}')$ . The second, more formal approach acknowledges the underlying molecular granularity, and supposes that  $\epsilon(\mathbf{r}, \mathbf{r}')$  is a short-ranged function such that,  $\epsilon(\mathbf{r}, \mathbf{r}') \simeq 0$  for  $|\mathbf{r} - \mathbf{r}'| > \ell_\epsilon$ . The characteristic length  $\ell_\epsilon$  is determined by molecular correlations, and previous simulation studies suggest  $\ell_\epsilon \approx 6 \text{ \AA}$ .<sup>23,24</sup> If  $\mathbf{E}$  varies slowly over distances comparable to  $\ell_\epsilon$ , then the nonlocal relation (Eq. 1) reduces to the local one (Eq. 2), with

$$\epsilon\mathbf{U} = \int d\mathbf{r}' \epsilon(\mathbf{r}, \mathbf{r}') - \mathbf{1}(\mathbf{r}, \mathbf{r}').$$

Interfaces between different media are treated as infinitely sharp boundaries within DCT. Any polarization in a medium then results in an induced surface charge  $\sigma_{\text{ind}}(\mathbf{x}) = \mathbf{P}(\mathbf{x}) \cdot \hat{\mathbf{n}}(\mathbf{x})$  that occupies a region of infinitesimal thickness, where  $\hat{\mathbf{n}}(\mathbf{x})$  is the local surface normal. Such a scenario is, of course, an idealization of physical reality;<sup>25</sup> as discussed above, liquid interfaces have a finite length scale  $\ell_{\text{int}}$ , which is on the order of 1 nm—or a few molecular diameters—for liquid water close to its triple point. The induced surface charge density is then understood to result from a physical charge distribution which is localized in the interfacial region, but with a thickness comparable to  $\ell_{\text{int}}$ . Molecular simulations suggest that such interfacial charge distributions may vary rapidly along  $z$ .<sup>9–13</sup> Local dielectric constants obtained from simulation exhibit similar structure.

While it is reasonable to suppose that the properties of a material may differ in regions close to the interface compared to those in bulk, the notion of a local dielectric

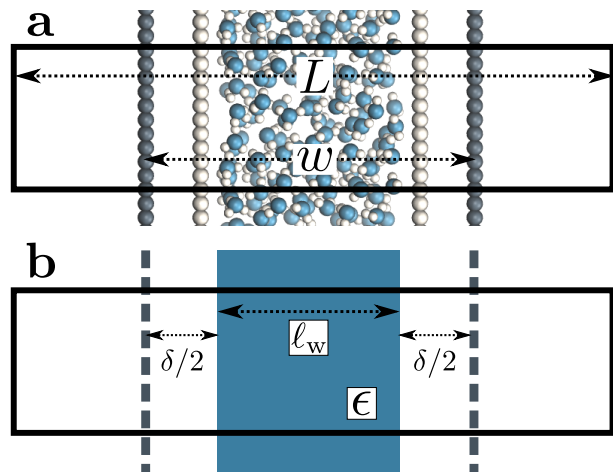


FIG. 1. Molecular and continuum representations of the system considered. (a) Water molecules (oxygen atoms in blue) are confined between volume-excluding WCA particles (light gray). Dark gray circles represent point charges: negative on the left, positive on the right, separated by a distance  $w$ . (b) In the continuum representation, these planes of point charges are approximated as uniformly charged sheets, as indicated by the dashed dark gray lines. The effect of the WCA particles enters implicitly by bounding the solvent, itself represented as a continuum with dielectric constant  $\epsilon$ , within a slab of thickness  $\ell_w = w - \delta$ , where  $\delta/2$  indicates the distance between the solvent-vapor dielectric boundary, and the charged planes. In both (a) and (b), the simulation cell is periodically replicated in all three dimensions, and its length in the direction normal to the charged planes is  $L$ .

constant with variations on the molecular scale is unsettling in a couple of respects. First, in going from the nonlocal constitutive relation specified by Eq. 1 to the local relation specified by Eq. 2, we assumed that fields vary slowly over length scales comparable to  $\ell_\epsilon \approx \ell_{\text{int}}$ , so one might therefore question the appropriateness of a local dielectric constant. Second, even if one is content with the locality of  $\epsilon(z)$ , DCT is a *macroscopic* theory, and the constitutive relations Eqs. 1 and 2 concern the *macroscopic* fields  $\mathbf{E}$  and  $\mathbf{P}$ . Obtaining these fields from the underlying microscopic degrees of freedom thus requires a coarse graining procedure, and it is reasonable to suppose that  $\ell_\epsilon$  sets the minimum length scale over which any such coarse graining should be performed. It is challenging to reconcile variations of  $\epsilon(z)$  on the molecular scale with this viewpoint of relating coarse grained macroscopic fields (Eqs. 1 and 2). By pursuing a thermodynamic perspective in this paper, which directly compares predictions of simple DCT to free energies obtained from molecular simulations, we avoid needing to compute the macroscopic fields  $\mathbf{E}$  and  $\mathbf{P}$  from microscopic degrees of freedom.

### III. USING SIMPLE DCT AS A FINITE SIZE CORRECTION

The extent of the physical systems we have in mind are microscopic in one direction (perpendicular to the interface) but otherwise macroscopic. To represent them in computer simulations, we take the standard approach of imposing periodic boundary conditions in all three Cartesian directions. Our simulated system is thus an infinite stack of thin water slabs, separated by substantial but still microscopic layers of vacuum, with an artificial periodicity. Because electrostatic interactions are long in range, we anticipate nonnegligible quantitative consequences of this periodicity, particularly when its repeat length is not significantly larger than the slab width.

To correct for such finite size effects, we adopt a strategy previously used to assess system size-dependence for ion solvation in similarly periodic slabs. Specifically, we extend our work in Ref. 26 to develop a finite size correction for the solvent contribution to the reversible work required to charge up a parallel plate capacitor under periodic boundary conditions (which we refer to as the ‘solvation’ free energy,  $f_{\text{solv}}^{(L)}$ ), based on the assumption that long-wavelength solvent response underlying finite size effects is well-described by DCT.<sup>27</sup> These predictions of DCT for charging parallel plates that bound thin water slabs serve simultaneously as a means to extrapolate computed free energies to the thermodynamic limit, and also as a test of the assumptions underlying DCT.

A representative snapshot of the system under consideration is shown in Fig. 1a. The parallel plate capacitor is approximated by two planes of  $N_{\text{site}}$  point charges arranged on a square lattice, located at  $z = \pm w/2$ . The total charge of the plane at  $z = w/2$  is  $Q = N_{\text{site}}q_{\text{site}}$ , which is equal-and-opposite to the plane at

$z = -w/2$ . The solvent water molecules are confined between these two charged planes by tightly packed volume-excluding Weeks-Chandler-Anderson<sup>28</sup> (WCA) particles (see Sec. IX). In most of what follows, the WCA centers and the point charges coincide, though we will also consider more general cases like those depicted in Fig. 1a. We now make two continuum approximations. First, water is treated as a dielectric slab with dielectric constant  $\epsilon$ , spanning  $z = -\ell_w/2$  to  $z = +\ell_w/2$ , as indicated in Fig. 1b. A value of  $\ell_w$  appropriate to our molecular system is not *a priori* obvious: The WCA particles enforce very low density of oxygen atoms outside a region  $-w/2 < z < w/2$ ; given that water molecules are not point particles, however, the most realistic continuum description could involve an offset  $\delta$  between  $w$  and  $\ell_w$ , i.e.,  $\ell_w = w - \delta$ . Considerations for choosing  $\delta$  will be discussed later.

The two charged planes at  $z = \pm w/2$  are treated in our continuum calculation as uniformly charged sheets with surface charge density  $q \equiv Q/A$ , where  $A$  is the cross-sectional area of the simulation cell orthogonal to  $z$ . Within DCT, these charged planes enter the continuum model explicitly by introducing a discontinuity of magnitude  $4\pi|q|$  in the total electric field along  $z$  (as the planes are surrounded on either side by vacuum), irrespective of whether they are coincident with the WCA particles. In contrast, the WCA centers only enter DCT implicitly by confining the water molecules such that the thickness of the dielectric slab is  $\ell_w \equiv w - \delta$ . The continuum representation of the system is summarized in Fig. 1b. The simulation cell is periodically replicated in all three dimensions, and the periodic length along the  $z$ -direction is  $L$ .

In the Supplementary Material (SM), we solve the periodic continuum problem shown schematically in Fig. 1b, obtaining a total electrostatic potential in the region  $-\ell_w/2 \leq z \leq \ell_w/2$

$$\phi(z) = 4\pi q \left( -\frac{zw}{L} + z \right) + 4\pi P \left( -\frac{z(w-\delta)}{L} + z \right), \quad (3)$$

where  $P$  is the uniform polarization of the dielectric, and we have assumed that an Ewald-style approach has been used to treat electrostatic interactions. The first term in Eq. 3 arises from the charged planes, which we denote  $\phi_q$ . The second term arises from the polarized dielectric, and we denote this  $\phi_{\text{solv}}$ . The total electric field inside the dielectric follows directly from Eq. 3:

$$E = -4\pi q \left( 1 - \frac{w}{L} \right) - 4\pi P \left( 1 - \frac{w-\delta}{L} \right). \quad (4)$$

We now combine Eq. 4 with the local constitutive relation

(Eq. 2) to obtain an expression for  $P$ :

$$P = -\frac{(\epsilon - 1)(1 - \frac{w}{L})q}{1 + (\epsilon - 1)(1 - \frac{w-\delta}{L})}. \quad (5)$$

We also show in the SM that the electrostatic potential at the charged plane at  $z = -w/2$  is

$$\phi_{\text{solv,lo}} = 2\pi P \left( \frac{w(w-\delta)}{L} - (w-\delta) \right). \quad (6)$$

Similarly, for the charged plate at  $z = +w/2$  we have

$$\phi_{\text{solv,hi}} = 2\pi P \left[ -\frac{w(w-\delta)}{L} + (w-\delta) \right]. \quad (7)$$

The solvation free energy  $f_{\text{solv}}^{(L)} = q(\phi_{\text{solv,hi}} - \phi_{\text{solv,lo}})/2$  is the difference in reversible work (per unit area) to introduce the surface charge density  $q$  to the charged planes with and without the solvent present. Combining Eqs. 5, 6 and 7 gives

$$f_{\text{solv}}^{(L)}(q) = -2\pi q^2(w - \delta) \frac{(\epsilon - 1)(1 - \frac{w}{L})^2}{1 + (\epsilon - 1)(1 - \frac{w - \delta}{L})}. \quad (8)$$

In the limit  $L \rightarrow \infty$  we recover the expected result

$$f_{\text{solv}}^{(\infty)}(q) = -2\pi q^2 \frac{\epsilon - 1}{\epsilon} (w - \delta). \quad (9)$$

The correction  $\Delta f_{\text{DCT}}(L) = f_{\text{solv}}^{(\infty)} - f_{\text{solv}}^{(L)}$  we should apply for finite  $L$  is thus

$$\Delta f_{\text{DCT}}(L) = 2\pi q^2(w - \delta)(\epsilon - 1) \left[ \frac{(1 - \frac{w}{L})^2}{1 + (\epsilon - 1)(1 - \frac{w - \delta}{L})} - \frac{1}{\epsilon} \right]. \quad (10)$$

Equation 10 provides a simple correction term that can be added to  $f_{\text{solv}}^{(L)}$  obtained from molecular simulations. The extent to which  $\Delta f_{\text{DCT}}(L)$  achieves consistent estimates of  $f_{\text{solv}}^{(\infty)}$  from simulations with different  $L$  is then one indicator of how well simple DCT describes the dielectric properties of water films.

#### IV. ASSESSING THE ACCURACY OF DCT WITH MOLECULAR SIMULATIONS

To assess our continuum prediction of the finite size correction  $\Delta f_{\text{DCT}}(L)$  given by Eq. 10, we will assume that  $\epsilon$  retains its bulk liquid value ( $\epsilon_{\text{liq}} \approx 71$  for SPC/E) over the entire domain  $-\ell_w/2 < z < \ell_w/2$ . The only undetermined parameter in Eq. 10 is then the length scale  $\delta$ , which determines the location of the dielectric boundaries of the solvent relative to the charged planes at  $z = \pm w/2$ . To determine an appropriate value of  $\delta$ , we note that DCT predicts an electric field due to the solvent in the region  $w/2 \leq z < L/2$

$$E_{\text{solv}} = 4\pi P \frac{(w - \delta)}{L}. \quad (11)$$

As shown in Fig. 2a,  $E_{\text{solv}}$  can be easily obtained from simulation. (Note that, owing to the charge asymmetric distribution of individual water molecules,  $\phi_{\text{solv}}(z)$  for liquid water varies across the interface even with  $q = 0 e/\text{\AA}^2$ . As we are concerned with the *response* of the dielectric slab, in Fig. 2a we have plotted  $\Delta_0\phi_{\text{solv}}(z) \equiv \phi_{\text{solv}}(z) - \phi_{\text{solv},0}(z)$ , where  $\phi_{\text{solv},0}(z)$  is the average electric potential profile with  $q = 0 e/\text{\AA}^2$ .)

For the time being, we consider cases where the charged planes and WCA centers coincide. For a given  $w$ , we then measure  $E_{\text{solv}}$  with  $q \approx 3 \times 10^{-3} e/\text{\AA}^2$  for each value of  $L$  investigated, and by combining Eqs. 5 and 11, we determine  $\delta$ . Results obtained with different  $w$  are shown in Fig. 2b. Despite some noise,  $\delta$  appears

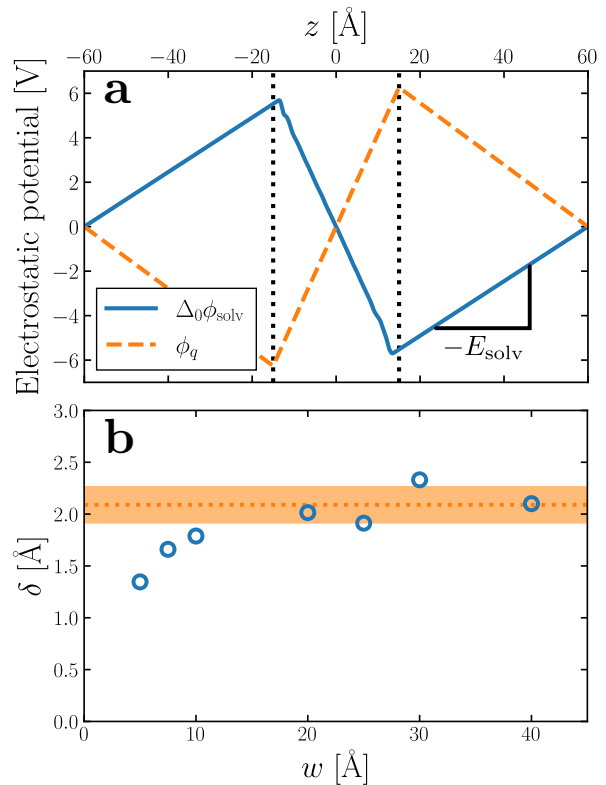


FIG. 2. (a) Average electrostatic potential due to the solvent (solid blue) and charged planes (dashed orange) with  $q \approx 3 \times 10^{-3} e/\text{\AA}^2$ ,  $w = 30 \text{\AA}$  and  $L = 120 \text{\AA}$ . The vertical dotted lines indicate the positions of the WCA particles. For the solvent, we plot  $\Delta_0\phi_{\text{solv}}(z) = \phi_{\text{solv}}(z) - \phi_{\text{solv},0}(z)$ , where  $\phi_{\text{solv},0}$  is the average potential with  $q = 0 e/\text{\AA}^2$ . The average electric field due to the solvent is used to determine  $\delta$ . (b) The inferred displacement  $\delta/2$  between WCA particles and the dielectric boundary depends only weakly on the width of the liquid slab. Each point in the plot of  $\delta$  vs.  $w$  is the average of 5 simulations with different values of  $L$ . Averaging results for  $w \geq 20 \text{\AA}$  gives  $\delta = 2.09 \pm 0.17 \text{\AA}$ , which is used throughout. The shaded orange region indicates a 95% confidence interval.

to plateau as  $w$  increases; averaging results for  $w \geq 20 \text{\AA}$ , we find  $\delta = 2.09 \pm 0.17 \text{\AA}$ .

Having determined  $\delta$ , we are now in a position to test the appropriateness of the finite size correction given by Eq. 10. To this end, in Figs. 3a and 3b, we show  $f_{\text{solv}}^{(L)}(q)$  for  $w = 40 \text{\AA}$  and  $w = 20 \text{\AA}$ , respectively. As expected,  $f_{\text{solv}}^{(L)}(q)$  exhibits a dependence on system size. Adding  $\Delta f_{\text{DCT}}(L)$  removes this dependence almost entirely, as seen in Figs. 3c and 3d. Also shown are results obtained by imposing vanishing electric displacement field  $D = 0 \text{ V/\AA}$  along  $z$ , which is formally equivalent to the commonly used Yeh-Berkowitz approach for approximating 2D Ewald summation.<sup>29,30</sup> As results obtained with  $D = 0 \text{ V/\AA}$  should approximate  $L \rightarrow \infty$ , they do not require a finite size correction. Importantly, excellent agreement with  $f_{\text{solv}}^{(L)} + \Delta f_{\text{DCT}}(L)$  is observed, giving us confidence that Eq. 10 provides a meaningful finite size

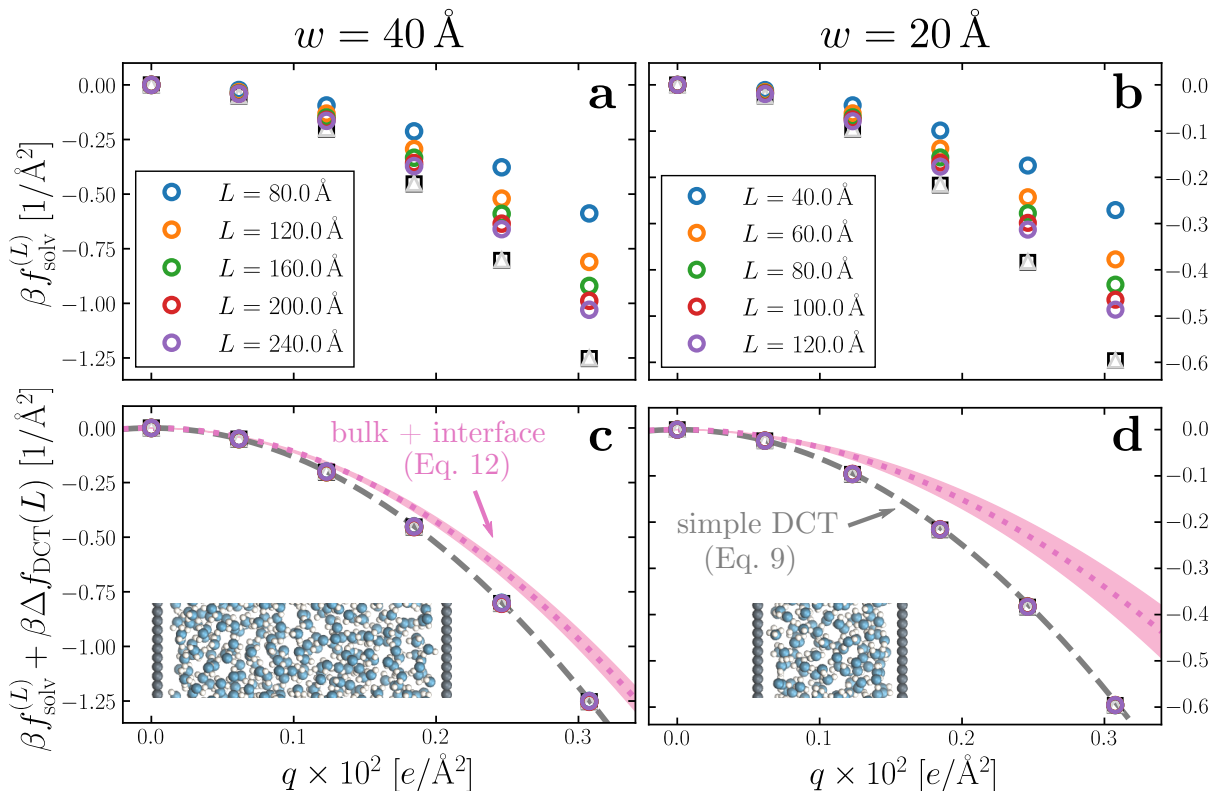


FIG. 3. Dependence of solvation free energy  $f_{\text{solv}}^{(L)}(q)$  on system size  $L$ , shown in (a) and (b) for  $w = 40 \text{ \AA}$  and  $w = 20 \text{ \AA}$ , respectively. The values of  $L$  for  $w = 40 \text{ \AA}$  are indicated in the legend of panel (a); those for the thinner liquid slab are shown in (b). Adding  $\Delta f_{\text{solv}}(L)$  given by Eq. 10 largely removes this sensitivity, as seen in (c) and (d) for  $w = 40 \text{ \AA}$  and  $w = 20 \text{ \AA}$ , respectively. DCT predictions for  $f_{\text{solv}}^{(\infty)}(q)$  (Eq. 9) are plotted as dashed gray lines. Black squares and gray triangles show results obtained with  $D = 0 \text{ V/\AA}$  for the smallest and largest values of  $L$ , respectively. The pink dotted lines show predictions of  $f_{\text{solv, int}}^{(\infty)}$  from a dielectric continuum model, in which an interfacial layer of width  $\ell_{\text{int}} = 7.5 \text{ \AA}$  is assigned a permittivity  $\epsilon_{\text{int}} = 2.1$  much lower than in bulk liquid, computed from (Eq. 12). The shaded regions bound predictions with  $6 \text{ \AA} \leq \ell_{\text{int}} \leq 9 \text{ \AA}$ . Insets: Snapshots from corresponding molecular dynamics simulations.

correction.

The fact that the simple DCT model outlined in Sec. III describes the finite size behavior of  $f_{\text{solv}}^{(L)}$  so well suggests it is reasonable to think of thin water films as having a uniform dielectric constant equal to that of bulk in the region they occupy. Even more tellingly, the extrapolation  $f_{\text{solv}}^{(L)} + \Delta f_{\text{DCT}}(L)$  from simulation agrees well with the continuum prediction  $f_{\text{solv}}^{(\infty)}$  in Eq. 9.

To provide a physical interpretation for the length scale  $\delta$ , Fig. 4 shows number density profiles  $\rho(z)$  for water's oxygen and hydrogen atoms from simulations with  $q = 0 \text{ e/\AA}^2$ . On these plots, we have also marked the boundary predicted by  $\ell_w/2 = (w - \delta)/2$ , which corresponds closely to the vanishing of average hydrogen density. Because the hydrogen atoms protrude further toward the vapor phase than the oxygen atoms, this boundary marks the outermost limit of microscopic sources of polarization fluctuations. The water film thickness we have inferred is thus the largest that could be reasonably justified based on the statistics of molecular configurations.

## V. ASSESSING THE VALIDITY OF OTHER MODELS

We have shown that  $f_{\text{solv}}^{(L)} + \Delta f_{\text{DCT}}(L)$  obtained from simulation agrees well with the predictions of a simple DCT in which the dielectric constant of thin films is identical to that of the bulk liquid. (Eq. 9). If we were to decrease  $\epsilon$ , agreement with simulation data would require assigning  $\ell_w$  a larger value than we have inferred, i.e., a value that would be difficult to justify from microscopic structure. This observation advocates against the notion that the overall dielectric permittivity of the thin film is lower than in the homogeneous fluid. By itself, however, it does not rule out a model in which the interfacial regions have a permittivity  $\epsilon_{\text{int}}$  that is distinct from the bulk region they sandwich. For such a model, the free energy reads

$$f_{\text{solv, int}}^{(\infty)} = -2\pi q^2 \left[ \ell_{\text{bulk}} \left( \frac{\epsilon - 1}{\epsilon} \right) + 2\ell_{\text{int}} \left( \frac{\epsilon_{\text{int}} - 1}{\epsilon_{\text{int}}} \right) \right]. \quad (12)$$

where  $\ell_{\text{int}}$  is the width of each interfacial region.

Following the dielectric imaging experiments of Fuma-

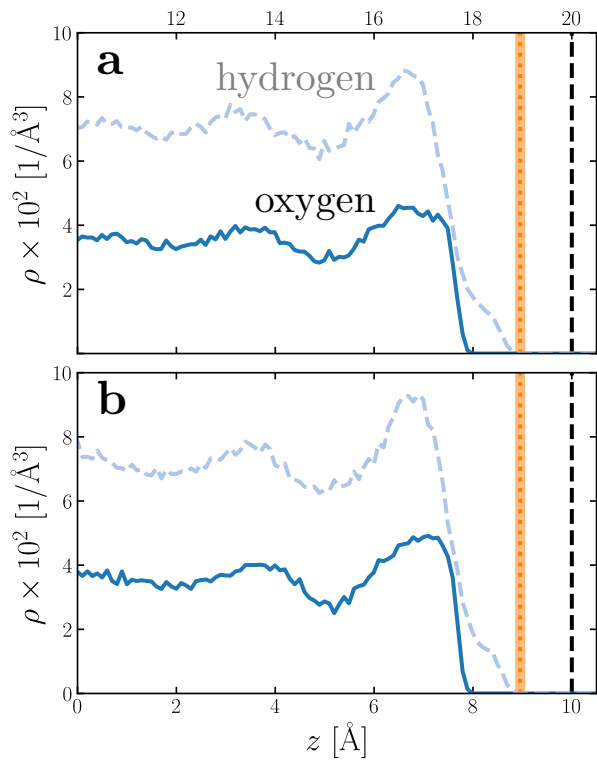


FIG. 4. Number density profiles  $\rho(z)$  for hydrogen (dashed blue) and oxygen (solid blue) atoms of water, with  $q = 0 \text{ e}/\text{\AA}^2$  for (a)  $w = 40 \text{ \AA}$  and (b)  $w = 20 \text{ \AA}$ . The vertical dashed line shows the location  $z = w/2$  of WCA particles, and the vertical dotted line indicates the dielectric boundary at  $z = (w - \delta)/2$ . (The shaded region indicates the same 95% confidence interval as in Fig. 2.) In both cases, the dielectric boundary aligns closely with the vanishing of hydrogen atom density.

galli *et al.*,<sup>6</sup> we take  $\ell_{\text{int}} = 7.5 \pm 1.5 \text{ \AA}$  and  $\epsilon_{\text{int}} = 2.1$ , and require the total width  $\ell_w = \ell_{\text{bulk}} + 2\ell_{\text{int}}$  to have the same value as in the uniform dielectric model: As discussed above, it is unreasonable to allow  $\ell_w$  to increase from that value. Decreasing  $\ell_w$ , on the other hand, offers less flexibility to a model that introduces regions of low dielectric constant at the expense of those with high dielectric constant. The resulting predictions of  $f_{\text{solv, int}}^{(\infty)}$  are shown in Figs. 3c and 3d (labeled ‘bulk+interface’), where poor agreement with the simulation data is observed. Quantitatively different (but not significantly improved) predictions would be obtained with different choices of  $\ell_{\text{int}}$  and  $\epsilon_{\text{int}}$ . We find generally that  $\ell_{\text{int}} = 0$  (or equivalently,  $\epsilon_{\text{int}} = \epsilon_{\text{liq}}$ ) yields the best agreement with simulation. Evidence for this conclusion is provided in SM.

The width  $\ell_{\text{int}}$  of a notional interfacial layer differs fundamentally from the length scale  $\delta$  in our simple uniform DCT. They can nonetheless easily be confused. In our case  $z = \pm(w - \delta)/2$  marks the location of a sharp interface between vapor and bulk liquid. This interface does not coincide with the location  $z = \pm w/2$  of the confining charged walls because their constituent WCA

particles exclude volume.  $\delta$  thus characterizes a region that is inaccessible to water molecules and should not be associated with the liquid. To emphasize this point, we modify the  $w = 20 \text{ \AA}$  system (Figs. 3b and 3d) by displacing the charged planes  $5 \text{ \AA}$  into vacuum, with the WCA particles fixed at their original positions (i.e., the general case considered in Fig. 1a).  $\delta$  increases by  $5 \text{ \AA}$  as a result, while  $\ell_w = w - \delta$  is unchanged, i.e.,  $w \rightarrow 30 \text{ \AA}$  and  $\delta \rightarrow 12.09 \text{ \AA}$ , while  $\ell_w = 17.91 \text{ \AA}$  just as before. Changing  $\delta$  in this fashion clearly has nothing to do with water’s interfacial dielectric properties. Fig. 5 presents results for  $f_{\text{solv}}^{(L)}$  and  $f_{\text{solv}}^{(L)} + \Delta f_{\text{DCT}}(L)$  for the displaced-charge system, which are virtually indistinguishable from their undisplaced counterparts in Fig. 3.

By contrast, a layer of width  $\ell_{\text{int}}$  in ‘bulk+interface’ models is clearly associated with the liquid. It is imagined to comprise water molecules whose orientational fluctuations are distinct from those in bulk liquid due to the phase boundary. Multiple studies based on such models have concluded that the interfacial layer has a greatly reduced polarizability, amounting to a ‘dead layer’ with  $\epsilon_{\text{int}} \approx 1$ .<sup>6,12–14,16,17</sup> Dielectric properties of this notional

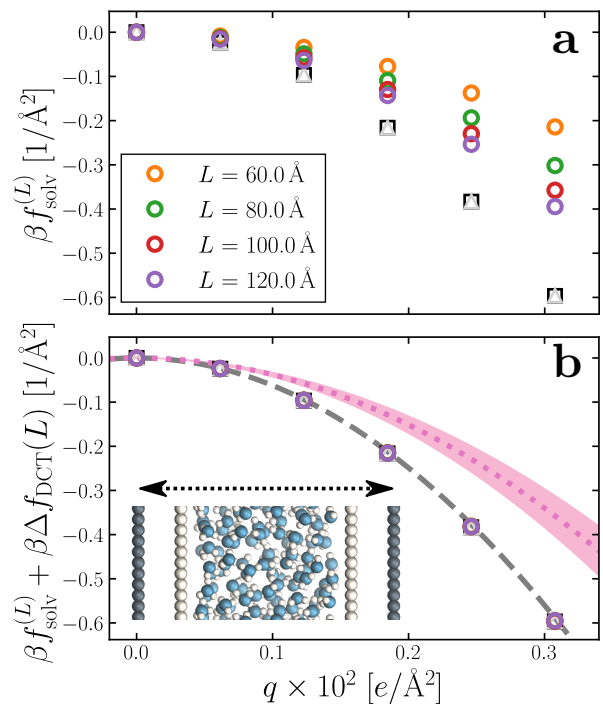


FIG. 5. Solvation free energies with the charged planes moved  $5 \text{ \AA}$  into vacuum. (a)  $f_{\text{solv}}^{(L)}(q)$  exhibits the same finite size dependence as in Fig. 3b, implying the same value of  $w - \delta$  and thus demonstrating that the layer of width  $\delta/2$  should not be associated with the liquid phase. (b) Adding  $\Delta f_{\text{DCT}}^{(\infty)}(L)$  to the results in (a), with  $w = 30 \text{ \AA}$  and  $\delta = 12.09 \text{ \AA}$ , essentially removes dependence on  $L$  entirely. Inset: Snapshot from a molecular dynamics simulation showing the position of the charged planes relative to the WCA centers (see Fig. 1). The double headed arrow indicates  $w$ .



dead layer may be nearly indistinguishable from vacuum, but the layer plainly belongs to the dense liquid phase within a ‘bulk+interface’ picture.

## VI. ULTRA THIN FILMS OF WATER

We have established so far that films of water with  $\ell_w \gtrsim 18 \text{ \AA}$  behave quantitatively like simple dielectric continua with regard to their response to a uniform electric field. We now investigate the behavior of ‘ultra thin’ films confined between charged plates with  $w \leq 10 \text{ \AA}$ . In Figs. 6a, 6b and 6c, we show  $f_{\text{solv}}^{(\infty)}$  obtained with simulation for  $w = 5 \text{ \AA}$ ,  $7.5 \text{ \AA}$ , and  $10 \text{ \AA}$ , respectively, using  $\delta = 2.09 \pm 0.17 \text{ \AA}$  to correct for finite size effects (Eq. 10). As the thickness of the water slab is reduced to length scales comparable to  $\ell_\epsilon \approx 6 \text{ \AA}$ , treating the water molecules as a dielectric continuum is certainly questionable. Discrepancies between  $f_{\text{solv}}^{(\infty)}$  (Eq. 9) and  $f_{\text{solv}}^{(L)} + \Delta f_{\text{DCT}}(L)$  indeed become apparent as  $w$  is decreased below  $1 \text{ nm}$ , but the relative error of continuum predictions is surprisingly modest. Even when  $w$  is only large enough to accommodate a single molecular layer (Fig. 6a), the continuum prediction in Eq. 9 provides a reasonable ballpark estimate of the solvation free energy. For two to three molecular layers (Fig. 6b and 6c), quantitative agreement between simple DCT and the simulation data is recovered almost entirely.

## VII. RECONCILING OUR RESULTS WITH DIELECTRIC IMAGING EXPERIMENTS

The conclusion we have drawn from computer simulations—that the dielectric response of nanoscopically thin water films can be anticipated from bulk properties alone—is squarely at odds with the conclusion drawn by Fumagalli *et al.*<sup>6</sup> based on dielectric imaging measurements of confined water. In this section we attempt to reconcile our results with those measurements. Assuming that our simple uniform continuum model is correct, we show how uncertainty in the thickness of a water film can cause the apparent dielectric constant  $\epsilon_{\text{app}}$  to depend sensitively on film thickness. More specifically, we assess the consequences of assigning a width  $l_w + \delta$  to a film whose actual thickness is  $l_w$ , i.e., failing to account for the volume excluded by a confining substrate. Based on this assignment and the development in Sec. III, we would expect a solvation free energy

$$f_{\text{solv,app}}^{(\infty)}(q) = -2\pi q^2 \frac{\epsilon_{\text{app}} - 1}{\epsilon_{\text{app}}} w. \quad (13)$$

Equating this with the ‘true’ free energy in Eq. 9, we obtain

$$\epsilon_{\text{app}}(w) = \left( 1 - \frac{\epsilon - 1}{\epsilon} \frac{w - \delta}{w} \right)^{-1}, \quad (14)$$

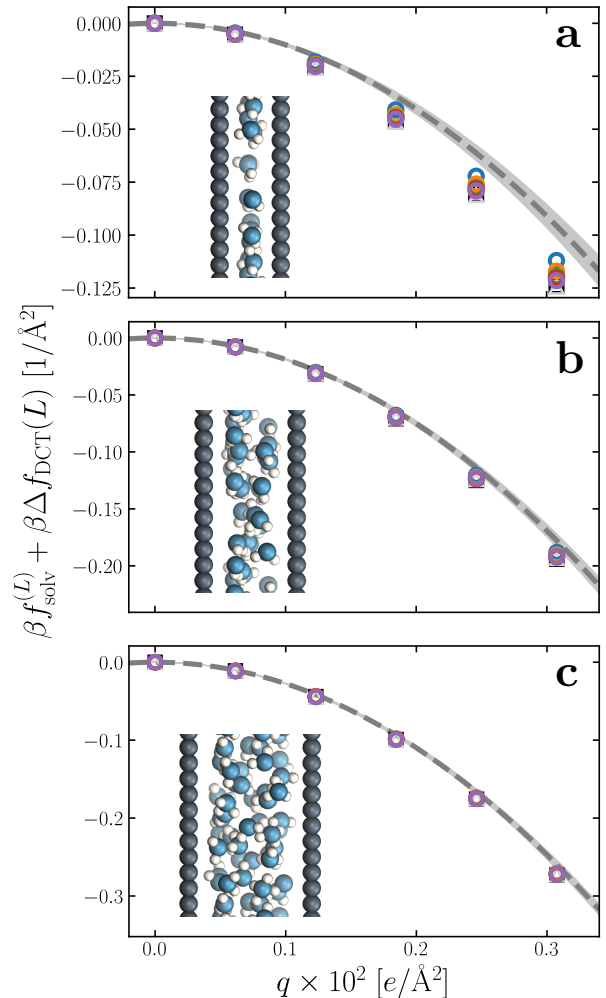


FIG. 6. Solvation free energy  $f_{\text{solv}}^{(\infty)}(q)$  in ultra thin water films, for (a)  $w = 5 \text{ \AA}$ , (b)  $w = 7.5 \text{ \AA}$ , and (c)  $w = 10 \text{ \AA}$ . For each value of  $w$ , simulations with  $L = 2w, 3w, \dots, 6w$  have been performed. The dashed line shows  $f_{\text{solv}}^{(\infty)}(q)$  predicted by DCT (Eq. 9), and the shaded region encompasses predictions with  $\delta = 2.09 \pm 0.17 \text{ \AA}$ . Insets: snapshots from molecular dynamics simulations.

which depends explicitly on the film’s thickness. While similar functional forms for  $\epsilon_{\text{app}}(w)$  have been reported previously,<sup>14,16</sup> the physical interpretation here is different: As discussed in Sec. V,  $\delta$  is not to be associated with the properties of interfacial water.

Fig. 7 plots the apparent permittivity  $\epsilon_{\text{app}}$  in Eq. 14 as a function of  $w$ . Here we have set  $\epsilon = \epsilon_{\text{liq}} = 80$  and estimated  $\delta \approx 3.5 \text{ \AA}$  for the graphene-water interface (based on density profiles obtained from *ab initio* molecular dynamics simulations<sup>31</sup>). Diminished values of  $\epsilon_{\text{app}}$  at small  $w$  could easily, *but mistakenly*, be taken to signify a strong suppression of polarization fluctuations and response in nanoscale water films.

The inference of suppressed interfacial permittivity from experiments may suffer from the same issues that

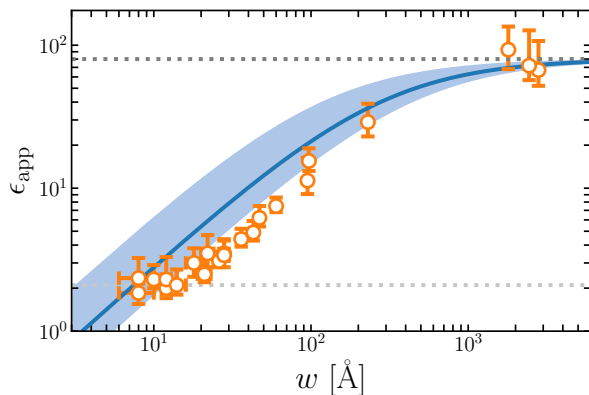


FIG. 7. The apparent dielectric constant  $\epsilon_{\text{app}}$  predicted by simple DCT (Eq. 14) is broadly consistent with experiment. The blue solid line is obtained with  $\delta = 3.5 \text{ \AA}$ , which is estimated from *ab initio* molecular dynamics simulations of water on graphene. The blue shaded region indicates the range of  $\epsilon_{\text{app}}$  obtained with  $\delta = 3.5 \pm 2.0 \text{ \AA}$ , demonstrating the sensitivity of  $\epsilon_{\text{app}}$  to uncertainty in the film thickness. The light and dark gray dotted lines indicate  $\epsilon_{\text{app}} = 2.1$  and  $\epsilon_{\text{app}} = 80$ , respectively.

cause  $\epsilon_{\text{app}}$  to depend strongly on film thickness. To emphasize this point, in Fig. 7 we include dielectric imaging data from Ref. 6, which exhibit a very similar dependence on  $w$ . As an important caveat, the samples studied by Fumagalli *et al.* have a more complicated geometry than the simple ‘slit-pore’ scenario we have considered, involving an AFM tip, multiple water channels, a graphite substrate, and hexagonal boron nitride walls. Since geometry of the dielectric boundary is precisely the issue under scrutiny here, the comparison between theory and experiment suggested by Fig. 7 should be made cautiously and only qualitatively. In our view it nonetheless suggests that the correct interpretation of measurements in Ref. 6 may not in fact require invoking an interfacial dead layer.

## VIII. SUMMARY

In this article, we have probed the dielectric response of thin water films using molecular simulations with finite size corrections from DCT. We specifically calculated the solvent contribution to the reversible work of introducing charge to parallel plates that confine the film. Our results demonstrate that response to such slowly varying external fields can be accurately captured with a DCT model whose permittivity is simply equal to that of the homogeneous liquid, in the entire region occupied by the liquid. Our analysis reveals that appropriate dielectric boundaries for these films extend to the point where the hydrogen number density approximately vanishes, and thus incorporate all microscopic sources of polarization fluctuations. This observation is consistent with our recent study, where we found that the dielectric boundary between water and spherical solutes was reasonably de-

scribed by the first peak in the solute-hydrogen radial distribution function.<sup>32</sup> Within this simple DCT approach, which achieves quantitative agreement with simulation for films  $\gtrsim 1 \text{ nm}$ , water’s interfacial regions do not enter as separate domains. We also demonstrated rough consistency with experiments<sup>6</sup> that had previously been interpreted to imply a dielectrically dead layer of water at the liquid’s boundary. This agreement is achieved by asserting that dielectric boundaries had previously not been placed appropriately.

Our conclusion is further supported by results for subnanometer water films that comprise one to three molecular layers. In these cases, one cannot sensibly discuss a bulk region, yet the simple DCT model still performs remarkably well. If anything, the apparent dielectric constant would need to *increase* to improve agreement with the free energy data. To be certain, applying simple DCT to these subnanometer films cannot be carefully justified (see Sec. II). Nonetheless, this *ad hoc* application of simple DCT to small length scales strongly argues against the notion of an interfacial region with low dielectric constant. Our conclusion is also in line with previous studies that have found corrections similar to  $\Delta f_{\text{solv}}(L)$  for the solvation of small spherical ions in water work remarkably well down to the nanometer scale, for both bulk<sup>27,33,34</sup> and interfacial systems.<sup>26</sup> Similarly, the simple DCT model described in this article has also been found to accurately capture mean field-like corrections for thin films of water where electrostatic interactions are treated in a short-ranged fashion.<sup>24</sup>

It would be incorrect, however, to conclude from our results that simple DCT gives a full account of polarization response at the liquid’s surface. Indeed, even in bulk liquid water, the charging of small spherical solutes is characterized by short-wavelength solvent response that is not well-described by simple continuum approaches.<sup>33</sup> In such cases, and in contrast to the thin films considered in this work,  $f_{\text{solv}}^{(\infty)}$  predicted by DCT is a poor estimate of that obtained from simulations.<sup>26,32</sup> The impact of such profound perturbations are even more pronounced for solutes near soft interfaces like that between water and its vapor, where distortions of the interface result in nonlinearities beyond the scope of current theoretical treatments.<sup>35</sup> But for perturbations that vary slowly in space, like the uniform fields considered here, the results of this study add to a growing body of work that supports a surprisingly simple view of water’s surface (and, by extension, thin films) as a dielectric medium: Its local permittivity is equivalent to the bulk dielectric constant, all the way down to nanometer length scales.

## IX. METHODS

All simulations followed the basic setup shown in Fig. 1a. Two planes of  $N_{\text{site}} = 100$  point charges were placed on a square lattice at  $z = \pm w/2$ . Water molecules, modeled with the SPC/E potential,<sup>36</sup> were confined to



the region  $-w/2 \leq z \leq w/2$  by volume-excluding WCA particles,<sup>28</sup> whose centers, for the most part, coincided with the point charges at  $z = \pm w/2$ . The interaction between an individual WCA particle and a water molecule is defined by

$$u_{\text{WCA}}(r) = \begin{cases} 4\varepsilon \left[ \left(\frac{\sigma}{r}\right)^{12} - \left(\frac{\sigma}{r}\right)^6 \right], & r \leq 2^{1/6}\sigma, \\ 0, & r > 2^{1/6}\sigma, \end{cases} \quad (15)$$

where  $\sigma = 2.5 \text{ \AA}$ ,  $\varepsilon = 0.1 \text{ kcal/mol}$ , and  $r$  is the distance between the WCA particle and the oxygen atom of the water molecule. As described in Sec. V, for  $w = 20 \text{ \AA}$ , we also performed simulations where the planes of point charges were displaced  $5 \text{ \AA}$  into vacuum, but leaving the rest of the system unchanged. For each value of  $w$ , simulations of 5 ns (following at least 100 ps of equilibration) were performed with  $q_{\text{site}}/e = 0, 1 \times 10^{-3}, \dots, 5 \times 10^{-3}$ . The total volume of the simulation cells was  $12.75 \text{ \AA} \times 12.75 \text{ \AA} \times L$ , where  $L$  takes values as indicated throughout the article.

All simulations were performed with the LAMMPS simulations package.<sup>37</sup> Lennard-Jones interactions between water molecules were truncated and shifted at  $10 \text{ \AA}$ . Long range electrostatic interactions were evaluated using particle-particle particle-mesh Ewald summation,<sup>38</sup> with parameters chosen such that the RMS error in the forces were a factor  $10^5$  smaller than the force between two unit charges separated by a distance of  $1.0 \text{ \AA}$ .<sup>39</sup> Where indicated in the text, the electric displacement field along  $z$  was set to zero, using the implementation given in Ref. 40. The geometry of the water molecules was constrained using the RATTLE algorithm.<sup>41</sup> Temperature was maintained at 298 K with a Nosé-Hoover chain thermostat<sup>42,43</sup> with a damping constant of 100 fs. A time step of 2 fs was used throughout. The number of water molecules used in the simulations is given in Table IX.

TABLE I. Number of water molecules  $N_{\text{wat}}$  for each value of  $w$  investigated (WCA centers coincide with point charges).

$w/\text{\AA}$	5	7.5	10	20	25	30	40
$N_{\text{wat}}$	14	27	41	93	125	143	206

The free energy of charging up parallel plate capacitors was computed by averaging electric potentials appropriately. Let  $\varphi_{\text{solv,hi}}^{(i)}(\mathbf{R}^N)$  and  $\varphi_{\text{solv,lo}}^{(j)}(\mathbf{R}^N)$  denote the instantaneous electric potentials due to the solvent with configuration  $\mathbf{R}^N$  at site  $i$  of one of the point charges in the plane at  $z = w/2$ , and site  $j$  in the plane at  $z = -w/2$ , respectively. The total solvation free energy  $F_{\text{solv}}^{(L)}(Q)$  is then defined by

$$\begin{aligned} \exp[-\beta F_{\text{solv}}(Q)] &= \langle \exp[-\beta Q \Delta\varphi_{\text{solv}}] \rangle_0^{(L)} \\ &= \int d(\Delta\varphi_{\text{solv}}) P^{(L)}(\Delta\varphi_{\text{solv}}; 0) \exp[-\beta Q \Delta\varphi_{\text{solv}}], \quad (16) \end{aligned}$$

where

$$\begin{aligned} \Delta\varphi_{\text{solv}}(\mathbf{R}^N) &= \frac{1}{N_{\text{site}}} \left( \sum_{i \in \text{hi}} \varphi_{\text{solv,hi}}^{(i)}(\mathbf{R}^N) - \sum_{j \in \text{lo}} \varphi_{\text{solv,lo}}^{(j)}(\mathbf{R}^N) \right) \\ &= \varphi_{\text{solv,hi}}(\mathbf{R}^N) - \varphi_{\text{solv,lo}}(\mathbf{R}^N); \quad (17) \end{aligned}$$

$P^{(L)}(\Delta\varphi_{\text{solv}}; Q)$  is the probability distribution of  $\Delta\varphi_{\text{solv}}$  in the presence of two charged planes with total charges  $\pm Q$ , in a simulation box of length  $L$ ; and  $\langle \cdot \rangle_0^{(L)}$  denotes an average over  $P^{(L)}(\Delta\varphi_{\text{solv}}; 0)$ .

Similar to our previous studies,<sup>26,32</sup>  $F_{\text{solv}}(Q)$  was computed using the MBAR algorithm.<sup>44</sup> The solvation free energies per unit area,  $f_{\text{solv}}^{(L)}$  that we consider are then obtained by dividing  $F_{\text{solv}}(Q)$  by the cross-sectional area of the simulation cell.

## SUPPLEMENTARY MATERIAL

Supplementary Material includes a detailed derivation of results obtained for the periodic continuum model presented in Sec. III. Results for the ‘bulk+interface’ model with different parameters are also presented.

## ACKNOWLEDGMENTS

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## DATA AVAILABILITY STATEMENT

The data that supports the findings of this study and input files for the simulations are openly available at the University of Cambridge Data Repository, <https://doi.org/10.17863/CAM.81959>.

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# Supplementary Material

## S1. DERIVATION

The system we consider is shown schematically in Fig. 1. Two planes with charge density  $\pm q$  are located at  $z = \pm w/2$ . We will consider a more general case than in the main article. Here, a linear dielectric occupies the region  $-(w/2 - \delta_{\text{lo}}) \leq z \leq (w/2 - \delta_{\text{hi}})$ , such that  $\delta_{\text{lo}} + \delta_{\text{hi}} = \delta$ ; while the electrostatic potential is sensitive to the values of  $\delta_{\text{lo}}$  and  $\delta_{\text{hi}}$ , we will show that  $\Delta f_{\text{DCT}}(L)$  only depends on their sum. The boundaries of the dielectric are situated at  $\xi_{\text{hi}} = w/2 - \delta_{\text{hi}}$  and  $\xi_{\text{lo}} = w/2 - \delta_{\text{lo}}$ . The polarization of the medium is  $P$ .

### Potential due to the charged plates

The potential due to the charged plates is,

$$\phi_q(z) = 4\pi \int_{\text{cell}} dz' \rho_q(z') J(z - z'), \quad (\text{S1})$$

with

$$\rho_q(z) = q[\delta_{\text{D}}(z - w/2) - \delta_{\text{D}}(z + w/2)], \quad (\text{S2})$$

where  $\delta_{\text{D}}(x)$  is the Dirac delta-function, and<sup>26,45,46</sup>

$$J(z) = \text{const.} + \frac{z^2}{2L} - \frac{|z|}{2}. \quad (\text{S3})$$

Inside the region occupied by the charged sheets,  $-w/2 \leq z \leq w/2$ , we have

$$\phi_q(z) = 4\pi q \left( -\frac{zw}{L} + z \right). \quad (\text{S4})$$

Similarly, for  $w/2 < z \leq L/2$ ,

$$\phi_q(z) = 4\pi q \left( -\frac{zw}{L} + \frac{w}{2} \right), \quad (\text{S5})$$

while for  $-L/2 \leq z < -w/2$ ,

$$\phi_q(z) = 4\pi q \left( -\frac{zw}{L} - \frac{w}{2} \right). \quad (\text{S6})$$

### Potential due to a uniformly polarized dielectric

A uniformly polarized dielectric generates the same electric potential as a charge distribution comprising two uniformly charged planes,

$$\rho_{\text{solv}}(z) = P[\delta_{\text{D}}(z - \xi_{\text{hi}}) - \delta_{\text{D}}(z + \xi_{\text{lo}})]. \quad (\text{S7})$$

This leads to the following potential,

$$\phi_{\text{solv}}(z) = 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} + \frac{1}{2}(|z + \xi_{\text{lo}}| - |z - \xi_{\text{hi}}|) \right] \quad (\text{S8})$$

For the region occupied by the dielectric we have  $(-\xi_{\text{lo}} \leq z \leq \xi_{\text{hi}})$ ,

$$\phi_{\text{solv}}(z) = 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + z + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} + \frac{\xi_{\text{lo}} - \xi_{\text{hi}}}{2} \right], \quad (\text{S9})$$

while for  $\xi_{\text{hi}} < z \leq L/2$

$$\phi_{\text{solv}}(z) = 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} + \frac{\xi_{\text{hi}} + \xi_{\text{lo}}}{2} \right], \quad (\text{S10})$$

and for  $-L/2 \leq z \leq -\xi_{\text{lo}}$  we have,

$$\phi_{\text{solv}}(z) = 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} - \frac{\xi_{\text{hi}} + \xi_{\text{lo}}}{2} \right]. \quad (\text{S11})$$

### The total potential

The total potential is simply the linear superposition of potentials due to the charged planes and the solvent,  $\phi(z) = \phi_q(z) + \phi_{\text{solv}}(z)$ . Most important for the derivation is the region  $-\xi_{\text{lo}} \leq z \leq \xi_{\text{hi}}$ ,

$$\phi(z) = 4\pi q \left( -\frac{zw}{L} + z \right) + 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + z + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} + \frac{\xi_{\text{lo}} - \xi_{\text{hi}}}{2} \right]. \quad (\text{S12})$$

The potential in each of the remaining regions is listed below.

For  $-L/2 \leq z < -w/2$ :

$$\phi(z) = 4\pi q \left( -\frac{zw}{L} - \frac{w}{2} \right) + 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} - \frac{\xi_{\text{hi}} + \xi_{\text{lo}}}{2} \right]. \quad (\text{S13})$$

For  $-w/2 \leq z < -\xi_{\text{lo}}$ :

$$\phi(z) = 4\pi q \left( -\frac{zw}{L} + z \right) + 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} - \frac{\xi_{\text{hi}} + \xi_{\text{lo}}}{2} \right]. \quad (\text{S14})$$

For  $\xi_{\text{hi}} < z \leq w/2$ :

$$\phi(z) = 4\pi q \left( -\frac{zw}{L} + z \right) + 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} + \frac{\xi_{\text{hi}} + \xi_{\text{lo}}}{2} \right]. \quad (\text{S15})$$

For  $w/2 < z \leq L/2$ :

$$\phi(z) = 4\pi q \left( -\frac{zw}{L} + \frac{w}{2} \right) + 4\pi P \left[ -\frac{z(\xi_{\text{hi}} + \xi_{\text{lo}})}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{2L} + \frac{\xi_{\text{hi}} + \xi_{\text{lo}}}{2} \right]. \quad (\text{S16})$$

Note that  $\xi_{\text{hi}} + \xi_{\text{lo}} = w - \delta$ , where  $\delta = \delta_{\text{hi}} + \delta_{\text{lo}}$ .

### Linear response

Equations S12–S16 provide general expressions for the total electrostatic potential for the periodic continuum model considered in Fig. 1. As  $P$  depends upon the electric field, a self-consistent solution is required. In the case that the dielectric medium is linearly responding, however, the solution is analytically tractable. Consider the electric field inside the dielectric. From Eq. S12 we find for  $-\xi_{\text{lo}} \leq z \leq \xi_{\text{hi}}$ ,

$$E = -4\pi q \left( 1 - \frac{w}{L} \right) - 4\pi P \left( 1 - \frac{w - \delta}{L} \right). \quad (\text{S17})$$

Applying the local constitutive relation,  $4\pi P = (\epsilon - 1)E$ , we find

$$P = -(\epsilon - 1) \left[ q \left( 1 - \frac{w}{L} \right) + P \left( 1 - \frac{w - \delta}{L} \right) \right], \quad (\text{S18})$$

or rearranging,

$$P = -\frac{(\epsilon - 1)(1 - \frac{w}{L})q}{1 + (\epsilon - 1)(1 - \frac{w-\delta}{L})}. \quad (\text{S19})$$

From Eq. S13, it is clear that the potential at the charged plate at  $z = -w/2$ , due to the polarized dielectric is

$$\phi_{\text{solv,lo}} = 2\pi P \left[ \frac{w(w-\delta)}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{L} - (w-\delta) \right]. \quad (\text{S20})$$

Similarly, for the charged plate at  $z = +w/2$  we have,

$$\phi_{\text{solv,hi}} = 2\pi P \left[ -\frac{w(w-\delta)}{L} + \frac{\xi_{\text{hi}}^2 - \xi_{\text{lo}}^2}{L} + (w-\delta) \right]. \quad (\text{S21})$$

The solvation free energy is  $f_{\text{solv}}^{(L)} = q(\phi_{\text{solv,hi}} - \phi_{\text{solv,lo}})/2$ . Combining Eqs. S20, S21 and S19 gives,

$$f_{\text{solv}}^{(L)} = -2\pi q^2(w-\delta) \frac{(\epsilon - 1)(1 - \frac{w}{L})^2}{1 + (\epsilon - 1)(1 - \frac{w-\delta}{L})}. \quad (\text{S22})$$

In the limit  $L \rightarrow \infty$  this gives,

$$f_{\text{solv}}^{(\infty)} = -2\pi q^2 \frac{(w-\delta)(\epsilon - 1)}{\epsilon}. \quad (\text{S23})$$

The finite size correction we must apply is  $\Delta f_{\text{DCT}}(L) = f_{\text{solv}}^{(\infty)} - f_{\text{solv}}^{(L)}$ . Thus,

$$\Delta f_{\text{DCT}}(L) = 2\pi q^2(w-\delta)(\epsilon - 1) \left[ \frac{(1 - \frac{w}{L})^2}{1 + (\epsilon - 1)(1 - \frac{w-\delta}{L})} - \frac{1}{\epsilon} \right]. \quad (\text{S24})$$

## S2. SENSITIVITY OF $f_{\text{solv,int}}^{(\infty)}$ TO $\epsilon_{\text{int}}$ AND $\ell_{\text{int}}$

In Fig. S1 we plot  $f_{\text{solv}}^{(L)}(q) + \Delta f_{\text{DCT}}(L)$  for  $w = 40 \text{ \AA}$  and  $w = 20 \text{ \AA}$  (see Fig. 3), but with  $f_{\text{solv,int}}^{(\infty)}$  (Eq. 12) parameterized with  $\epsilon_{\text{int}} = 10$  and  $\ell_{\text{int}} = 6.0 \pm 1.5 \text{ \AA}$ . We argue that  $\ell_{\text{int}} = \ell_\epsilon \approx 6 \text{ \AA}$  sets a lower bound on reasonable values of  $\ell_{\text{int}}$ . As discussed in the main article, increasing  $\epsilon_{\text{int}}$  and decreasing  $\ell_{\text{int}}$ , while imposing the constraint  $\ell_w = \ell_{\text{bulk}} + 2\ell_{\text{int}}$  will obviously reduce discrepancies between  $f_{\text{solv,int}}^{(\infty)}$  and  $f_{\text{solv}}^{(L)}(q) + \Delta f_{\text{DCT}}(L)$ , as evidenced by Fig. S1. Nonetheless, it is clear that  $f_{\text{solv}}^{(\infty)}$  given by Eq. 9 still provides a superior description of the simulation data.



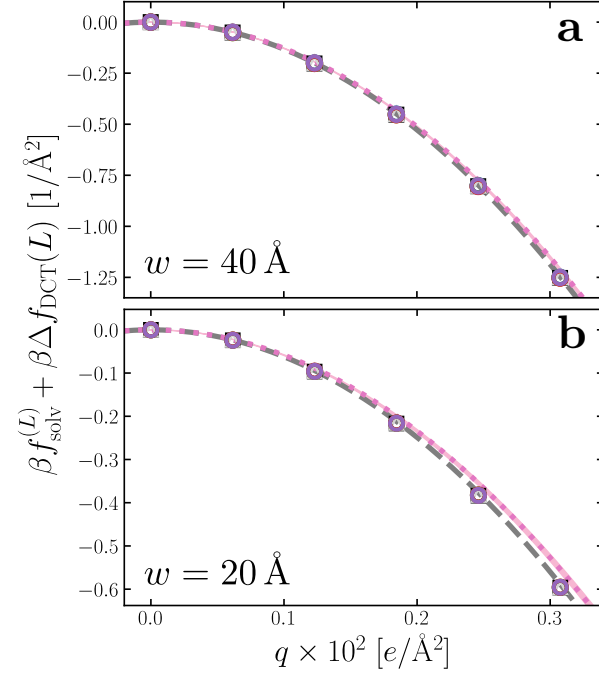


FIG. S1.  $f_{\text{sol}}^{(L)}(q) + \Delta f_{\text{DCT}}(L)$  with (a)  $w = 40 \text{\AA}$  and (b)  $w = 20 \text{\AA}$ . These data are the same as shown Figs. 3c and 3d, except  $f_{\text{sol, int}}^{(\infty)}$  (pink dotted lines) is plotted with  $\epsilon_{\text{int}} = 10$  and  $\ell_{\text{int}} = 6.0 \pm 1.5 \text{\AA}$ . While discrepancies between  $f_{\text{sol, int}}^{(\infty)}$  and  $f_{\text{sol}}^{(L)}(q) + \Delta f_{\text{DCT}}(L)$  are reduced compared to Figs. 3c and 3d,  $f_{\text{sol}}^{(\infty)}$  given by Eq. 9 (gray dashed lines) still gives a superior description of the simulation data.